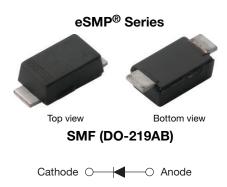


Vishay Semiconductors

Ultrafast Rectifier, 2 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|----------------|--|--|--|
| I _{F(AV)} | 2 A | | | |
| V _R | 600 V | | | |
| V _F at I _F | 0.95 V | | | |
| t _{rr} | 55 ns | | | |
| T _J max. | 175 °C | | | |
| Package | SMF (DO-219AB) | | | |
| Circuit configuration | Single | | | |

FEATURES

 \bullet Ultrafast recovery time, reduced $\mathbf{Q}_{\mathrm{rr}},$ and soft recovery



COMPLIANT HALOGEN

FREE

• 175 °C maximum operating junction temperature

For PFC CRM, snubber operation

• Low forward voltage drop

· Low leakage current

 \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

Meets JESD 201 class 2 whisker test

• Wave and reflow solderable

Compatible to SOD-123W package case outline

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMF (DO-219AB)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

Polarity: color band denotes cathode end

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|---|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Peak repetitive reverse voltage | V_{RRM} | | 600 | V |
| Average rectified forward current | I _{F(AV)} | T _C = 135 °C ⁽¹⁾ | 2 | ۸ |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C, 6 ms square pulse | 30 | А |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +175 | °C |

Note

(1) Device on PCB with 8 mm x 16 mm soldering lands



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| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|--|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 600 | - | - | |
| Forward voltage | V | I _F = 2 A | - | 1.10 | 1.35 | V |
| Forward voitage | V_{F} | I _F = 2 A, T _J = 150 °C | - | 0.95 | 1.15 |] |
| Reverse leakage current | , | V _R = V _R rated | - | - | 3 | |
| Reverse leakage current | $T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$ | - | 20 | 100 | μA | |
| Junction capacitance | C _T | V _R = 600 V | - | 5 | - | pF |

| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|-----------------|---|--|------|------|------|---------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | | $I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | 42 | - | |
| Reverse recovery time | | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$ | | - | - | 55 | |
| neverse recovery time | t _{rr} | T _J = 25 °C | I _F = 2 A dI _F /dt = 500 A/μs V _R = 400 V | - | 40 | - | ns - |
| | | T _J = 125 °C | | - | 63 | - | |
| Deals were supplied to | | T _J = 25 °C | | - | 7.0 | - | ^ |
| Peak recovery current I _{RRM} | IRRM | T _J = 125 °C | | - | 8.1 | - | Α |
| Davieres resolvent charge | 0 | T _J = 25 °C | | - | 140 | - | nC |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 255 | - | 110 |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|--|------|--------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | +175 | °C |
| Thermal resistance, junction to mount | R_{thJM} | Device mounted on PCB with 8 mm x 16 mm soldering lands | - | - | 15 | °C/W |
| Thermal resistance, junction to ambient | R _{thJA} | Device mounted on PCB with 2 mm x 3.5 mm soldering lands | - | - | 130 | °C/W |
| Approximate weight | | | | 0.015 | · | g |
| Approximate weight | | | | 0.0005 | | oz. |
| Marking device | | Case style SMF (DO-219AB) | | М | PU | |

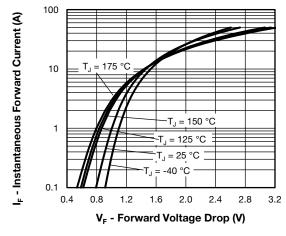


Fig. 1 - Typical Forward Voltage Drop Characteristics

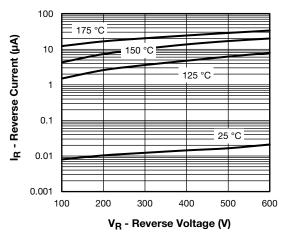


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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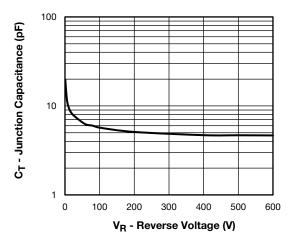


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

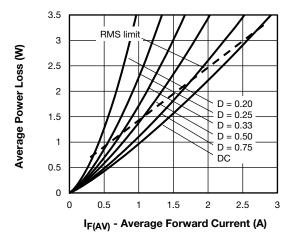


Fig. 5 - Forward Power Loss Characteristics

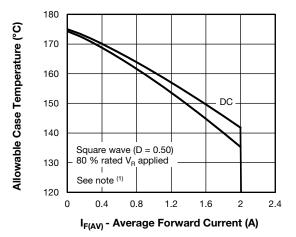


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

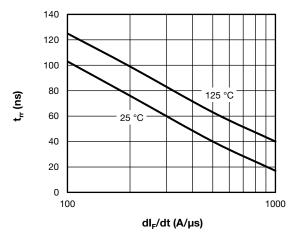


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

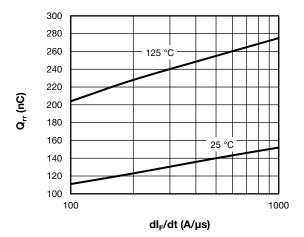
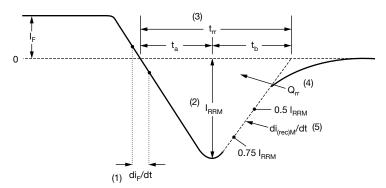


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 5)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

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- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{r}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

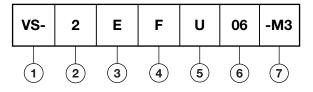
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating (2 = 2 A)
- 3 Circuit configuration:

E = single diode

- 4 F = SMF package
- 5 Process type,

U = ultrafast recovery

- 6 Voltage code (06 = 600 V)
- 7 -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

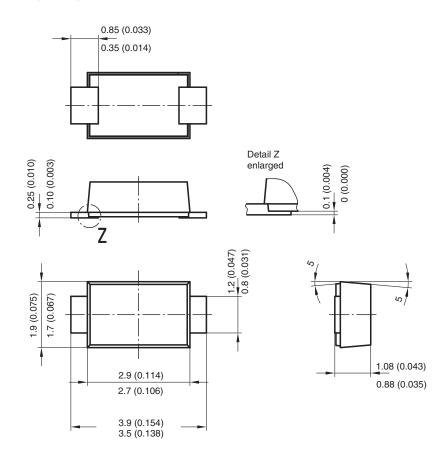
| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-------------------|------------------------|-----------------------------------|--|--|
| PREFERRED P/N | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-2EFU06-M3/I | 10 000 | 10 000 | 13"diameter plastic tape and reel | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95572 | | | |
| Part marking information | www.vishay.com/doc?95618 | | | |
| Packaging information | www.vishay.com/doc?95577 | | | |
| SPICE model | www.vishay.com/doc?96867 | | | |

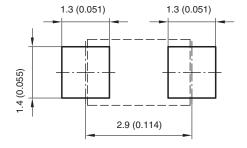
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SMF (DO-219AB)

DIMENSIONS in millimeters (inches)



Foot print recommendation:



Created - Date: 15. February 2005 Rev. 3 - Date: 13. March 2007 Document no.:S8-V-3915.01-001 (4) 17247



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